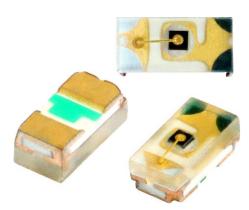
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RoHS

COMPLIANT

<u>(5-2008)</u>

Ultrabright 0402 ChipLED



DESCRIPTION

The new ChipLED series have been designed in the smallest SMD package. This innovative ChipLED technology opens the way to

- · smaller products of higher performance
- more design in flexibility
- enhanced applications

The 0402 LED is an obvious solution for small-scale, high brightness products that are expected to work reliable in an arduous environment.

PRODUCT GROUP AND PACKAGE DATA

• Product group: LED

Package: SMD 0402 ChipLED
Product series: standard
Angle of half intensity: ± 65°

FEATURES

- Super thin ChipLED with exceptional brightness
 1.0 mm x 0.5 mm x 0.35 mm (L x W x H)
- · High reliability PCB based
- Wavelength (470 to 475) nm (blue), typ. 571 nm (yellow green), (587 to 597) nm (yellow), typ. 605 nm (soft orange), typ. 631 nm (super red)
- AllnGaP and InGaN technology
- Viewing angle: extremely wide 130°
- Grouping parameter: luminous intensity, wavelength, V_F
- Available in 8 mm tape on 7" diameter reel
- · Compatible to IR reflow soldering
- · Preconditioning: according to JEDEC level 2a
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Backlight keypads
- · Navigation systems
- · Cellular phone displays
- · Displays for industrial control systems
- · Miniaturized color effects
- Traffic displays

PARTS TABLE	:											
PART	COLOR	LUMIN	OUS INT (mcd)	ENSITY	at I _F	WA	VELENO (nm)	STH	FORWARD VOLTAGE (V)		TECHNOLOGY	
		MIN.	TYP.	MAX.	(IIIA)	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
VLMS1500-GS08	Super red	18	54	-	20	-	631	-	1	2.0	2.4	AllnGaP
VLMO1500-GS08	Soft orange	45	90	-	20	-	605	-	-	2.0	2.4	AllnGaP
VLMY1500-GS08	Yellow	28	-	180	20	587	-	597	-	2.0	2.4	AllnGaP
VLMG1500-GS08	Yellow green	18	35	-	20	-	571	-	-	2.0	2.4	AllnGaP
VLMB1500-GS08	Blue	11.2	-	45	5	470	-	475	2.65	-	3.15	InGaN

	ATINGS (T_{amb} = 25 °C, unless oth VLMY1500, VLMG1500 (AllnGa		d)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage (1)		V_R	5	V
DC forward current		I _F	30	mA
Surge forward current	1/10 duty cycle, 0.1 ms pulse width	I _{FSM}	80	mA
Power dissipation	T _{amb} ≤ 25 °C	P_V	75	mW
Operating temperature range		T _{amb}	- 30 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 85	°C
IRED solder conditions	according Vishay specifications	T _{st}	260	°C

Note

(1) Driving the LED in reverse direction is suitable for short term application



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ABSOLUTE MAXIMUM RAVLMB1500 (InGaN technol	ATINGS ($T_{amb} = 25 ^{\circ}\text{C}$, unless othogy)	nerwise specified	d)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
DC forward current		I _F	20	mA
Surge forward current	1/10 duty cycle, 0.1 ms pulse width	I _{FSM}	100	mA
Power dissipation	T _{amb} ≤ 25 °C	P _V	76	mW
Operating temperature range		T _{amb}	- 20 to + 80	°C
Storage temperature range		T _{stg}	- 30 to + 100	°C
IRED solder conditions	according Vishay specifications	T _{st}	260	°C

OPTICAL AND ELECTRIC VLMS1500, SUPER RED	AL CHARACTERISTICS (T _{al}	_{mb} = 25 °C, uı	nless othe	erwise spe	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	18	54	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	-	631	-	nm
Peak wavelength	I _F = 20 mA	λ_{p}	-	639	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	20	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Reverse current	V _R = 5 V	I _R	-	-	10	μΑ

OPTICAL AND ELECTRICATION OF THE VLMO1500, SOFT ORANG		_{mb} = 25 °C, u	nless othe	erwise spe	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	45	90	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	=	605	-	nm
Peak wavelength	I _F = 20 mA	λ_{p}	=	611	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	17	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Reverse current	V _R = 5 V	I _R	-	-	10	μΑ

OPTICAL AND ELECTRIC VLMY1500, YELLOW	AL CHARACTERISTICS (T _{ar}	_{mb} = 25 °C, u	nless othe	rwise spe	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	28	-	180	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	587	-	597	nm
Peak wavelength	I _F = 20 mA	λρ	-	588	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	15	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Reverse current	V _R = 5 V	I _R	-	-	10	μA



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OPTICAL AND ELECTRIC VLMG1500, YELLOW GR	CAL CHARACTERISTICS (T _{ar} Een	_{mb} = 25 °C, ui	nless othe	erwise spe	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	Ι _V	18	35	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	-	571	-	nm
Peak wavelength	I _F = 20 mA	λρ	-	574	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	15	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz	Cj	-	40	-	pF
Reverse current	V _R = 5 V	I _R	-	-	10	μA

OPTICAL AND ELECTRIC VLMB1500, BLUE	AL CHARACTERISTICS (Ta	_{lmb} = 25 °C, ui	nless othe	erwise spe	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 5 mA	I _V	11.2	-	45	mcd
Dominant wavelength	I _F = 5 mA	λ_{d}	470	-	475	nm
Peak wavelength	I _F = 5 mA	λ_{p}	-	468	-	nm
Angle of half intensity	$I_F = 5 \text{ mA}$	φ	-	± 65	-	deg
Spectral line half width	I _F = 5 mA	Δλ	-	25	-	nm
Forward voltage	I _F = 5 mA	V _F	2.65	-	3.15	V
Reverse current	V _R = 5 V	I _R	-	-	10	μA

LUMINOUS INTENSITY CLASSIFICATION						
GROUP	LUMINOUS IN	TENSITY (mcd)				
GROUP	MIN.	MAX.				
L	11.2	18				
М	18	28				
N	28	45				
Р	45	71				
Q	71	112				
R	112	180				
S	180	280				
T	280	450				

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 15 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CL	ASSIFICAT	ION	
COLOR	GROUP	DOMINANT W	VAVELENGTH m)
		MIN.	MAX.
	J	587	589.5
Yellow	K	589.5	592
reliow	L	592	594.5
	М	594.5	597
	С	567.5	570.5
Yellow green	D	570.5	573.5
	E	573.5	576.5
Blue	AD	470	475

Note

 Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.

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COLOR	CROUP	FORWARD VO	OLTAGE (V)
COLOR	GROUP	MIN.	MAX.
	D2	1.8	2.0
Yellow	D3	2.0	2.2
	D4	2.2	2.4
	4	1.9	2
	5	2	2.1
Yellow green	6	2.1	2.2
	7	2.2	2.3
	8	2.3	2.4
	1	2.65	2.75
	2	2.75	2.85
Blue	3	2.85	2.95
	4	2.95	3.05
	5	3.05	3.15

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

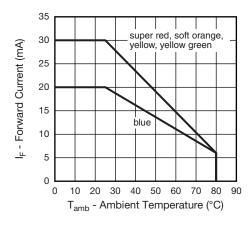


Fig. 1 - Forward Current vs. Ambient Temperature

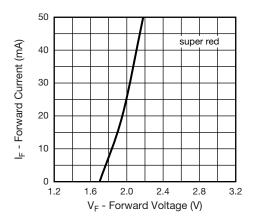


Fig. 2 - Forward Current vs. Forward Voltage (super red)

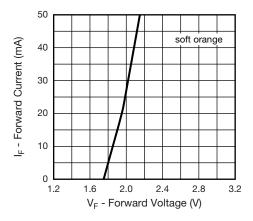


Fig. 3 - Forward Current vs. Forward Voltage (soft orange)

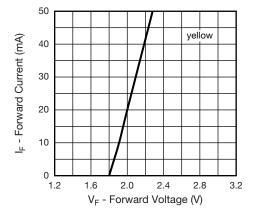


Fig. 4 - Forward Current vs. Forward Voltage (yellow)

[•] Forward voltage is measured with a tolerance of ± 0.1 V.

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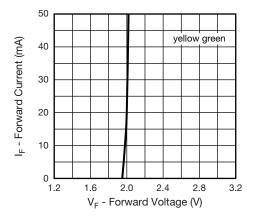


Fig. 5 - Forward Current vs. Forward Voltage (yellow green)

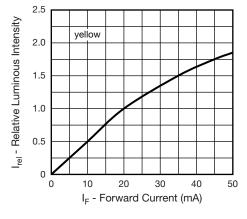


Fig. 8 - Relative Luminous Intensity vs. Forward Current (yellow)

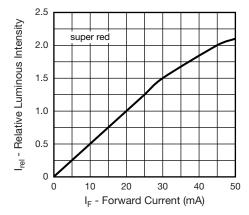


Fig. 6 - Relative Luminous Intensity vs. Forward Current (super red)

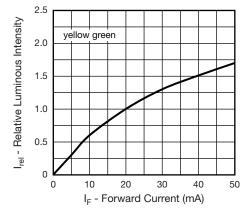


Fig. 9 - Relative Luminous Intensity vs. Forward Current (yellow green)

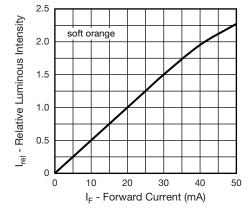


Fig. 7 - Relative Luminous Intensity vs. Forward Current (soft orange)

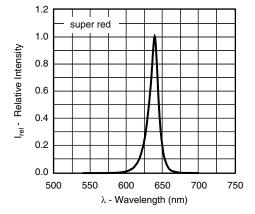


Fig. 10 - Relative Intensity vs. Wavelength (super red)

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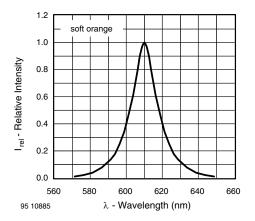


Fig. 11 - Relative Intensity vs. Wavelength (soft orange)

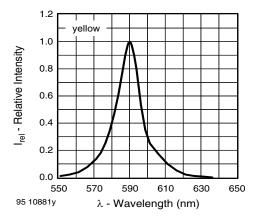


Fig. 12 - Relative Intensity vs. Wavelength (yellow)

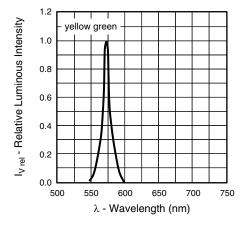


Fig. 13 - Relative Intensity vs. Wavelength (yellow green)

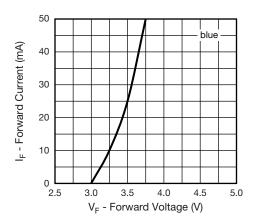


Fig. 14 - Forward Current vs. Forward Voltage (blue)

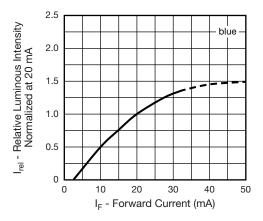


Fig. 15 - Relative Luminous Intensity vs. Forward Current (blue)

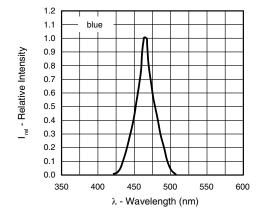


Fig. 16 - Relative Intensity vs. Wavelength (blue)

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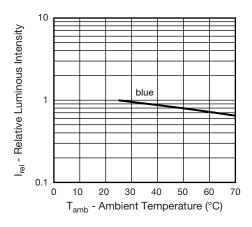


Fig. 17 - Relative Luminous Intensity vs. Ambient Temperature

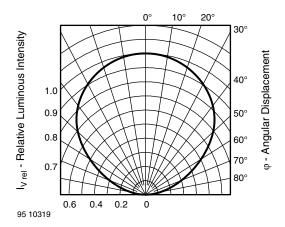
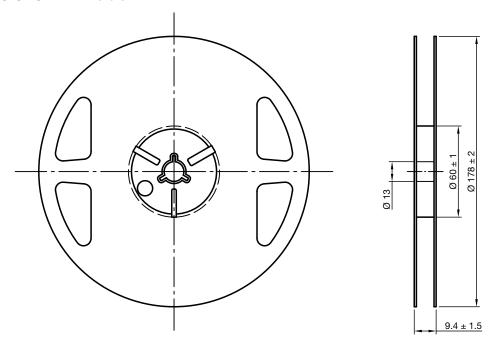


Fig. 18 - Relative Luminous Intensity vs. Angular Displacement

REEL DIMENSIONS in millimeters



Drawing-No.: 9.800-5122.01-4 Issue: 2; 03.11.11

22611

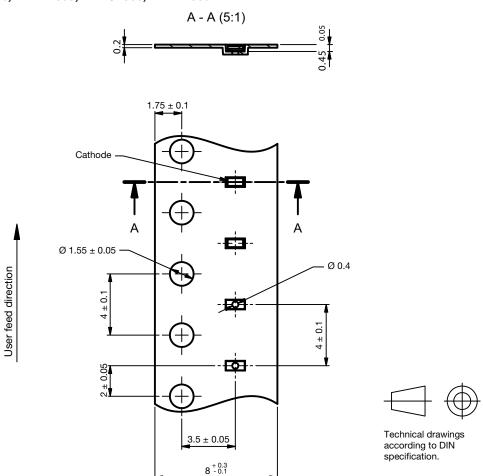
technical drawings according to DIN specifications



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TAPE DIMENSIONS in millimeters

VLMS1500, VLMO1500, VLMY1500, VLMG1500, VLMB1500



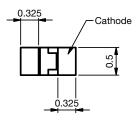
Drawing-No.: 9.700-5388.01-4

Issue: 1; 20.03.12

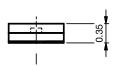
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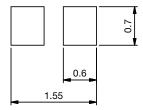
PACKAGE DIMENSIONS in millimeters

VLMS1500, VLMO1500, VLMY1500, VLMG1500, VLMB1500



Recommended solder pad footprint









Technical drawings according to DIN specification



Not indicated tolerances ± 0.2

Drawing-No.: 6.541-5096.01-4

Issue: 1; 20.03.12

SOLDERING PROFILE

IR Reflow Soldering Profile for lead (Pb)-free Soldering Preconditioning acc. to JEDEC Level 2

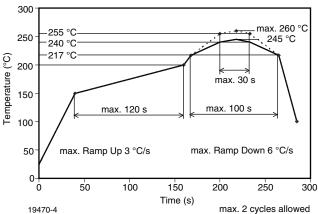
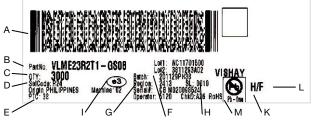


Fig. 19 - Vishay Lead (Pb)-free Reflow Soldering Profile (according to J-STD-020C)

BAR CODE PRODUCT LABEL (example only)



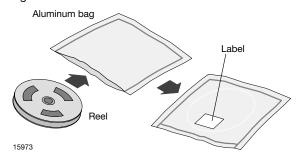
- A) 2D barcode
- B) Vishay part number
- C) Quantity
- D) PTC = selection code (binning)
- E) Code of manufacturing plant
- F) Batch = date code: year/week/plant code
- G) Region code
- H) SL = sales location
- I) Terminations finishing
- K) Lead (Pb)-free symbol
- L) Halogen-free symbol
- M) RoHS symbol



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DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

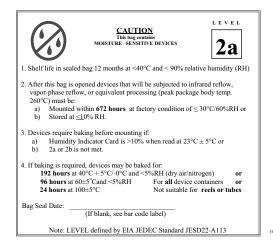
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen)

96 h at 60 °C + 5 °C and < 5 % RH for all device containers

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC Standard JESD22-A112 Level 2a label is included on all dry bags.



Example of JESD22-A112 Level 2a Label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Legal Disclaimer Notice

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.